



Pressure Sensors

for Industrial, Automotive, Medical and Consumer Applications

www.epcos.com

Welcome to the World of Electronic Components and Modules



EPCOS is a leading manufacturer of electronic components, modules and systems. Our broad portfolio includes capacitors, inductors and ferrites, EMC filters, sensors and sensor systems, nonlinear resistors, and arresters, as well as SAW and BAW components and RF modules. As an innovative technology-driven company, EPCOS focuses technologically demanding growth markets in the areas of information and communications technology, automotive, industrial, and consumer electronics. We offer our customers both standard components as well as application-specific solutions.

EPCOS has design, manufacturing and marketing facilities in Europe, Asia and the Americas. We are continuously strengthening our global research and development network by expanding R&D activities at our production locations, primarily in Eastern Europe, China and India. With our global presence we are able to provide our customers with local development and manufacturing know-how and support in the early phases of their projects.

EPCOS is continually improving its processes and thus the quality of its products and services. The Group is ISO/TS 16949 certified and remains committed to constantly reviewing and systematically improving its quality management system.

Pressure Sensors for Industrial, Automotive, Medical and Consumer Applications



The high precision of piezoresistive sensor dies and the customization of the pressure sensors to specific requirements allow their versatile use in a wide range of applications.

Pressure sensors supply measured data for industrial equipment and systems in order to control and diagnose hydraulically or pneumatically operated machines. This makes them to key components in measurement and control technology.

Pressure sensors are also used in the automotive industry to minimize emissions of noxious exhaust gases and soot particles. Their high reliability is equally vital in air conditioning, engine management, powertrain electronics and brake systems in utility vehicles as well as for measuring pressure in respiratory, anesthesia equipment, blood pressure monitoring and cleaning technology in the medical sector.

EPCOS pressure sensors supply exact data within the scope of measuring liquid and gaseous media.

Equipped with miniaturized barometric pressure sensors, navigation devices can measure the altitude and – together with a GPS-provided location – very precisely determine the 3D position. Applications include navigation devices with 3D maps or position information accurate to within one story of a building for emergency calls from mobile phones.

Important Notes

The following applies to all products named in this publication:

- 1. Some parts of this publication contain statements about the suitability of our products for certain areas of application. These statements are based on our knowledge of typical requirements that are often placed on our products in the areas of application concerned. We nevertheless expressly point out that such statements cannot be regarded as binding statements about the suitability of our products for a particular customer application. As a rule, EPCOS is either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always ultimately incumbent on the customer to check and decide whether an EPCOS product with the properties described in the product specification is suitable for use in a particular customer application.
- 2. We also point out that in individual cases, a malfunction of electronic components or failure before the end of their usual service life cannot be completely ruled out in the current state of the art, even if they are operated as specified. In customer applications requiring a very high level of operational safety and especially in customer applications in which the malfunction or failure of an electronic component could endanger human life or health (e.g. in accident prevention or life-saving systems), it must therefore be ensured by means of suitable design of the customer application or other action taken by the customer (e.g. installation of protective circuitry or redundancy) that no injury or damage is sustained by third parties in the event of malfunction or failure of an electronic component.
- 3. The warnings, cautions and product-specific notes must be observed.

- 4. In order to satisfy certain technical requirements, some of the products described in this publication may contain substances subject to restrictions in certain jurisdictions (e.g. because they are classed as hazardous). Useful information on this will be found in our Material Data Sheets on the Internet (www.epcos.com/material). Should you have any more detailed questions, please contact our sales offices.
- 5. We constantly strive to improve our products. Consequently, **the products described in this publication may change from time to time**. The same is true of the corresponding product specifications. Please check therefore to what extent product descriptions and specifications contained in this publication are still applicable before or when you place an order.

We also **reserve the right to discontinue production and delivery of products**. Consequently, we cannot guarantee that all products named in this publication will always be available.

The aforementioned does not apply in the case of individual agreements deviating from the foregoing for customer-specific products.

- 6. Unless otherwise agreed in individual contracts, all orders are subject to the current version of the "General Terms of Delivery for Products and Services in the Electrical Industry" published by the German Electrical and Electronics Industry Association (ZVEI).
- 7. The trade names EPCOS, BAOKE, Alu-X, CeraDiode, CSMP, CSSP, CTVS, DSSP, MiniBlue, MiniCell, MKK, MLSC, MotorCap, PCC, PhaseCap, PhaseCube, PhaseMod, PhiCap, SIFERRIT, SIFI, SIKOREL, SilverCap, SIMDAD, SIMID, SineFormer, SIOV, SIP5D, SIP5K, ThermoFuse, WindCap are **trademarks registered or pending** in Europe and in other countries. Further information will be found on the Internet at www.epcos.com/trademarks.

General Information

Piezoresistive pressure measurement

The pressure measurement in sensor dies operates on the basis of the piezoresistive effect, occurring in diaphragm, in which piezoresistors are implanted onto the surface.

The micromechanical etched diaphragm contains a wheatstone bridge. The silicon wafer is connected with a glass base by anodic bonding to ensure the restraint at the edges.

The mechanical bending stress by pressure application causes a change in the piezoresistors. The output of the powered bridge is a voltage signal (mV range) proportional to the pressure.



Absolute pressure sensor dies are bonded to a solid glass base under vacuum.

Gauge pressure sensor dies have a glass base with a hole, so that the reference pressure is applicable on the back side.

Absolute pressure – application on the front

The glass base encloses the reference pressure for the absolute pressure measurements on the back. The measured medium comes into contact with the active electronic components. Only dry and non-aggressive media may be measured.



Absolute pressure application on the back

To measure wet media, the reference pressure is enclosed on the front. The pressure is applied to the back where is no contact with active electronic components.

Typical applications are altitude measurements in ballons or barometric measurements for meteorological use.



Alternative types for easy mounting with glass base on back side are also available.



Differential pressure

The pressure difference is measured with the help of making a hole in the glass base. The polarity of the bridge output signal changes depending on the side, where the pressure is higher.

A differential pressure sensor can be used for flow measurement by measuring the pressure drop along a gas stream.



Gauge pressure

Gauge pressure measurement is a case of differential pressure measurement, where the measurement is related to the actual air pressure. A typical application is the liquid level indication.

Gauge symmetrical pressure

In case of gauge symmetrical pressure, the measurement is related to equally over and under the actual air pressure.

The various arts of pressure measurement are due to the reference pressure related to measured pressure.

General Information



EPCOS offers various designs of piezoresistive pressure measurement devices – from simple pressure sensor dies via packaged pressure transducers and transmitters up to customer-specific pressure-sensor systems.

Every design is based on sensor dies developed and manufactured in our own cleanrooms.

Bonded and integrated into a standard package, the pressure transducer is processed directly on the circuit board.

The pressure transmitters are extended by a signal evaluation module and supplied with or without a stainless steel case in readyto-mount form or for simple circuit board assembly.

Typical applications

Industry

- Hydraulic and pneumatic systems
- Measurement and control technology
- Environmental and climate protection
- Gas analyzers and meters
 Heating, ventilation and air conditioning systems in buildings

Automotive

- Exhaust recuperation
- Soot particle filters
- Air conditioning
- Engine management
- Powertrain electronics
- Utility vehicle brakes

Medicine

- Respiration technology
- Anesthesia equipment
- Blood pressure monitoring
- Cleaning equipment

Consumer

- Barometric measurements in portable electronics such as mobile phones, personal navigation devices and watches
- Hard disk drives (HDD)
- Cycling computers
- Cameras with altimeter function

Features

- Piezoresistive silicon technology
- Absolute, differential and gauge pressure measurement
- Extensive range of pressure measurements
- High measurement accuracy
- Various packaging forms
- Sensor elements for humid/
- wet operating environmentsRoHS-compatible

Pressure Units

Conversion ta	Conversion table for pressure units											
bar	psi	kPa	cm H₂O	inch H₂O	mm Hg	lbf/ft ²						
0.016	0.232	1.6	16.32	6.43	12.0	33.416						
0.025	0.363	2.5	25.49	10.04	18.8	52.213						
0.040	0.58	4.0	40.79	16.06	30.0	83.54						
0.060	0.87	6.0	61.18	24.09	45.0	125.31						
0.100	1.45	10.0	101.97	40.15	75.0	208.85						
0.160	2.32	16.0	163.2	64.25	120.0	334.16						
0.250	3.63	25.0	254.9	100.35	188.0	522.125						
0.400	5.8	40.0	407.9	160.59	300.0	835.4						
0.600	8.7	60.0	611.8	240.87	450.0	1253.1						
1.000	14.5	100.0	1019.7	401.46	750.0	2088.5						
1.600	23.2	160.0	1632.0	642.52	1200.0	3341.6						
2.500	36.3	250.0	2549.0	1003.54	1875.0	5221.25						
4.000	58.0	400.0	4079.0	1605.91	3000.0	8354.0						
6.000	87.0	600.0	6118.0	2408.66	4500.0	12531.0						
10.00	145.0	1000.0	10197.0	4014.57	7501.0	20885.0						
16.00	232.0	1600.0	16316.0	6423.62	12001.0	33416.0						
25.00	363.0	2500.0	25494.0	10037.01	18752.0	52212.5						
40.00	580.0	4000.0	40790.0	16059.06	30002.0	83540.0						
60.00	870.0	6000.0	61184.0	24088.19	45003.0	125310.0						
100.0	1450.0	10000.0	101974.0	40147.24	75006.0	208850.0						

Overview

Pressure s	ensor dies	, transducers and tr	ansmitters	
Туре	Description			Characteristics
Pressure sen	sor dies			Page 10-13
	Pressure sen an anodically Gauge press well as absol available. The C29 and pressure mea The difference reference pre the pressure	sor dies consist of a piezo / bonded glass base. ure sensor dies with press lute pressure sensor dies asurements in wet media. to conventional absolute assure chamber which is b is applied to the back side	resistive silicon element with ure to front and back side as with pressure to front side are were developed for absolute e pressure sensor dies is the onded to the front side and e.	 Piezoresistive MEMS technology Square diaphragm Whetstone bridge with mV output ratiometric to supply voltage Anodically bonded glass base Options Temperature sensing diode HPSP High-performance solder joint pressure die (back side solderable die) in
	Туре	Rated pressure range	Pressure measurement	development
Come - Co	C41	0.025 0.060 bar	Gauge back side	
	C27	0.250 1.000 bar 0.100 1.000 bar	Absolute, front side Gauge, back side	
	C28	2.500 25.00 bar	Absolute, front side Gauge, back side Gauge, front side	
	C29	1.000 10.00 bar	Absolute, back side	
Selection of	C32	1.600 25.00 bar	Absolute, back side Absolute, front side Gauge, back side	
geometries.	C33	1.200 bar	Absolute, front side	
Pressure sen	sor transduc	ers		Page 14-15
	The robust s mechanical of The output s	isor dies from our own clea tainless steel/plastic casin decoupling. ignal is neither calibrated r	 Whetstone bridge with mV output ratiometric to supply voltage RoHS-compatible, halogen-free Dual-in-line package for PCB mounting Options 	
	Туре	Rated pressure range	Pressure measurement	Pressure port 4.8 mm tube fitting
	AK2	0.025 25.00 bar	Gauge	Pressure port M5 thread
	AT2 absolute con pressure The robust s decoupling. The output s	pressure transducers are e sensor dies from our own tainless steel casing featur ignal is not calibrated nor t	based on piezoresistive sili- cleanroom production facility. res excellent mechanical remperature compensated.	 Piezoresistive MEMS technology Whetstone bridge with mV output ratiometric to supply voltage RoHS-compatible, halogen-free TO39 package for PCB mounting
F. C.	Туре	Rated pressure range	Pressure measurement	
	AT2	1.600 25.00 bar	Absolute	
	The ASB 120 pressure trar The output s	00 E is an SMT-mountable sducer with a stainless sto ignal is neither calibrated r	gel-protected barometric eel pressure port. 1or temperature compensated.	 Piezoresistive MEMS technology Whetstone bridge with mV output ratiometric to supply voltage RoHS-compatible, halogen-free
	Type	Rated pressure range	Pressure measurement	SMT ceramic package for PCB mounting
		1 200 bar	Abcoluto	
0018T	T5100 press The bridge si compensatio	ure transducers are based ignal is available uncalibra n.	on C33 pressure sensor dies. ted and without temperature	 Piezoresistive full bridge Smallest CSMP[™] package For high-volume consumer applications RoHS-compatible, halogen-free
	Туре	Rated pressure range	Pressure measurement	
	T5100	1.200 bar	Absolute	

Overview

Pressure s	ensor dies	, transducers and tr	ansmitters	
Туре	Description			Characteristics
Pressure sense	sor transmitte	ers		Page 16-23
	CAU-T press represent ter pressure sen The electroni temperature	ure transmitters with and water nperature compensated ar sors. cs of the CAU-T series con errors of the piezo-resistive	without stainless steel casing and calibrated precision mpensate linearity and e measurement circuit.	 Piezoresistive MEMS technology RoHS-compatible, halogen-free Options Stainless steel casing (pressure port G1/8" thread) Without casing (pressure port M5 thread) Voltage output 0.5 4.5 V Current output 4 20 mA
	Туре	Rated pressure range	Pressure measurement	
	CAU-T	1.000 25.00 bar 0.100 25.00 bar 0.100 1.000 bar	Absolute Gauge Gauge, symmetrical	
	The AC-T pre series. They suitable for ir	essure transmitters offer al are completely calibrated a tegration in control blocks	I advantages of the CAU-T and simply to replace, hence s and circuit boards.	 Piezoresistive MEMS technology Voltage output: 0.5 4.5 V RoHS-compatible, halogen-free Dual-in-line package for PCB mounting Options Pressure port 4.8 mm tube fitting Pressure port M5 thread
	Туре	Rated pressure range	Pressure measurement	
	AC-T	1.000 2.500 bar 0.100 25.00 bar 0.100 1.000 bar	Absolute Gauge Gauge, symmetrical	
	The ASB 120 protected ba pressure por sensor die, w with a semic temperature	0 V1 and ASB 1200 VR arr rometric pressure transmit t. The heart of these new tr hich is mounted in hybrid onductor ASIC. The voltag compensated.	e SMT-mountable gel- ters with a stainless steel ransmitters is a piezoresistive technology together e output is calibrated and	 Piezoresistive MEMS technology Voltage output: 01 V or ratiometric to V_{cc} RoHS-compatible, halogen-free SMT ceramic package for PCB mounting
	Туре	Rated pressure range	Pressure measurement	
	ASB 1200 V1 ASB 1200 VR	0.200 1.200 bar 0.200 1.200 bar	Absolute Absolute	
	T5300/T5400 calibrated wi) pressure transmitters, ter th digital (I ² C and SPI) inte	nperature-compensated and rface	 Digital output, serial interface Smallest CSMP[™] package For high-volume consumer applications RoHS-compatible, halogen-free Options Customized calibrated pressure range Customized accuracy
	Туре	Rated pressure range	Pressure measurement	
	T5300 T5400	0.3 1.1 bar 0.3 1.1 bar	Absolute Absolute	

9

Pressure Sensor Dies

Technical data											
Туре		C41		C27							
Pressure measurement		Gauge		Absolute							
Measured media		Non-aggressive fluids	and gases	Dry non-aggre	essive gases						
Output signal		۳۱	/, not calibrated, not te	mperature-con	npensated						
Pressure from		Back side		Front side							
Construction		↑	Glass		↓ 	— Silicon — Glass ^{TDS00124-E}					
Dimensions				I							
Die size	mm	5.05 imes 5.05		3.05 imes 3.05							
Total height	mm	0.9		0.9							
Glass thickness	mm	0.5		0.5							
Hole diameter	mm	1.6		-							
Maximum ratings				1							
Storage temperature T _{st}	°C	-40 +150		-40 +150							
Operating temperature T _a	°C	-40 +135		-40 +135							
Supply voltage (max.) V _{DD}	V	10		10							
Temperature characteristics $V_{DD} = 3$	5 V			1							
Temperature coefficients α_{RS}	10 ⁻³ /K	2.4		2.4							
of the bridge resistance (typ.) β_{RS}	10 ⁻⁶ /K ²	6		6							
Temperature coefficients α_s of the sensitivity (typ.) β_s	10 ⁻³ /K 10 ⁻⁶ /K ²	-2.2 5		-2.2 5							
Temperature coefficient TCV _F of diode flow voltage (typ.)	mV/K	-2.2		-2.2							
Characteristics $T_a = 25 \text{ °C}$, $V_{DD} = 5 \text{ V}$	V										
Bridge resistance (min./max.) R_s	kΩ	4.0 6.0		2.6 4.0							
Offset voltage (min./max.) V_0	mV	-25 +25		-30 +30							
Diode flow voltage (typ.) V_F at $I_F = 50 \ \mu A$	mV	600		600							
Nonlinearity (typ.) L	%FS	±1	±0.75	±0.2		±0.3					
Sensitivity (typ.) S	mV/bar	1000	700	400	300	120					
Output span (typ.) V _{Sp} @p _r	mV	25	42	100	120	120					
Rated pressure p _r	bar	0.025	0.060	0.250	0.400	1.000					
Ordering code ¹⁾	0 bar.	58601G5010A001	58601G5010A002	58600C5010A003	58600C5010A004	58600C5010A005					
Other values on request.		Ő	ä	ä	ä	Ш Ш					



0.9	1.2	1.2	1.2
0.5	0.8	0.8	0.8
0.7	-	0.4	0.4
-40 +150	-40 +150	-40 +150	-40 +150
-40 +135	-40 +135	-40 +135	-40 +135
10	10	10	10
2.4 6	2.4 6	2.4 6	2.4 6
-2.2 5	-2.2 5	-2.2 5	-2.2 5
-2.2	-2.2	-2.2	-2.2

2.6 4	l.0			2.7 3	3.7			2.7 3	3.7			2.7 3	3.7			
-25	+25			-30	+30			-30 ·	+30			-30 •	-30 +30			
600	600				600				600							
±0.5	±0.35	±0.2	±0.2	±0.2	±0.2							±0.2				
500	400	300	120	48	20	12	4.8	48	20	12	4.8	48	20	12	4.8	
50	100	120	120	120	120							120	120			
0.100	0.250	0.400	1.000	2.500	6.000	10.00	25.00	2.500	6.000	10.00	25.00	2.500	6.000	10.00	25.00	
B58601C5010A006	B58601C5010A007	B58601C5010A008	B58601C5010A009	B58600D8010A011	B58600D8010A012	B58600D8010A013	B58600D8010A014	B58601D8010A016	B58601D8010A017	B58601D8010A018	B58601D8010A019	B58601D8010A024	B58601D8010A025	B58601D8010A026	B58601D8010A027	

Pressure Sensor Dies

Technical data										
Туре		C29				C29				
Pressure measurement		Absolute				Absolute				
Measured media				Non	-aggressive	fluids and g	ases			
Output signal			m	V, not calibr	ated, not te	emperature-	compensat	ted		
Pressure from		Back side	e	,	,	Back side				
Construction			, 	GI	ass top licon ₂soo17-3-€			GI	ass top licon ass ₂soos-x-€	
Dimensions										
Die size	mm	2.2 × 2.7				2.2×2.7				1
Total height	mm	0.8				1.6				
Glass thickness	mm	0.4				0.4 front,	0.8 back			
Hole diameter	mm	-				0.4				
Maximum ratings						1				
Storage temperature T _{st}	°C	-40 +1	50			-40 +1	50			
Operating temperature T	°C	-40 +1	35			-40 +1	35			
Supply voltage (max.) V _{DD}	V	10				10				
Temperature characteristics V = 5	v					l				1
Temperature characteristics $v_{DD} = 0$	10-2/14	0.0								1
of the bridge resistance (typ.) β_{RS}	10 ⁻⁶ /K ²	2.2 6				6				
Temperature coefficients α_s of the sensitivity (typ.) β_s	10 ⁻³ /K 10 ⁻⁶ /K²	–2.2 5				-2.2 5				
Temperature coefficient TCV _F of diode flow voltage (typ.)	mV/K	-2.2				-2.2				
Characteristics $T_a = 25 \degree C$, $V_{DD} = 5 V$,									
Bridge resistance (min./max.) R _s	kΩ	2.1 3.3	3			2.1 3.3				
Offset voltage (min.) V_0	mV	-65	-55	-45	-35	-65	-55	-45	-35	
Offset voltage (max.) V ₀	mV	+30	+30	+30	+30	+30	+30	+30	+30	
Diode flow voltage (typ.) V_F at $I_F = 50 \ \mu A$	mV	600				600				
Nonlinearity (typ.) L	%FS	±0.2				±0.2				
Sensitivity (typ.) S	mV/bar	85	50	30	13	85	50	30	13	
Output span (typ.) V _{Sp} @p _r	mV	85	125	120	130	85	125	120	130	
Rated pressure p _r	bar	1.000	2.500	4.000	10.00	1.000	2.500	4.000	10.00	
Ordering code ¹⁾ ¹⁾ Rated pressure range 1.000 25.00	58600E0410A020	58600E0410A021	58600E0410A022	58600E0410A023	58600E0410A002	58600E0410A003	58600E0410A004	58600E0410A005		
Other values on request.		ä	ä	Ĕ	ä	ä	ä	ä	Ĕ	



2.3	2.3	2.3	2.4
5	5	5	6
-2.2	-2.2	-2.2	-2.2
5	5	5	5
-	-	-	

	2.6 4	.0			2.6 4	.0			2.6 4	1.0			2.6 4.0
	-50	-40	-35	-30	-30				-25	5			-30
	+25	+25	+25	+25	+30				+25				+30
	-				-				-				-
	±0.2				±0.2				±0.2				±0.3
	70	30	12	4.8	70	30	12	4.8	70	30	12	4.8	100
	112	120	120	120	112	120	120	120	112	120	120	120	120
	1.600	4.000	10.00	25.00	1.600	4.000	10.00	25.00	1.600	4.000	10.00	25.00	1.200
	B58600H8400A037	B58600H8400A039	B58600H8400A038	B58600H8400A040	B58600H8000A001	B58600H8000A002	B58600H8000A003	B58600H8000A004	B58601H8000A035	B58601H8000A033	B58601H8000A036	B58601H8000A034	B5860010000A001

Pressure Transducers

Transducers

Technical data												
Туре		AK2, K	D types				AK2, K0	C types				
Pressure measurement		Gauge										
Measured media					Non-a	ggressive	fluids and	d gases				
Output signal				mV, no	t calibrate	ed, not te	emperatur	re-compe	ensated			
Terminal assignment				Supply v Supply v	oltage V _c oltage V _c	₀ _{□-} : Pin 1, ₀: Pin 3,	Output v Output v	oltage V	_{but+} : Pin 2, _{but-} : Pin 4			
Dimensional drawings in mm		KD type	KD type, tube fitting KC type, thread connection									
			1.5	Top v 0.25	View	3.5	SW10 ME		Top \ 2.25	/iew		
Maximum ratings							1					1
Storage temperature T _{st}	°C	-40	+125				-40	⊦125				
Operating temperature T _a	°C	-30	+85				-30	⊦85				
Supply voltage (max.) V _{DD}	V	10					10					
Temperature characteristics $V_{DD} = 5$	v											
Temperature coefficients α_{RS} of the bridge resistance (typ.) β_{RS}	10 ⁻³ /K 10 ⁻⁶ /K ²	2.4 6					2.4 6					
Temperature coefficients $\alpha_{\rm S}$ of the sensitivity (typ.) $\beta_{\rm S}$	10 ⁻³ /K 10 ⁻⁶ /K ²	–2.2 5					-2.2 5					
Characteristics $T_a = 25 \text{ °C}$, $V_{DD} = 5 \text{ V}$												
Bridge resistance (typ.) R _s	kΩ	5.0	5.0	3.3	3.3	3.3	3.3	3.2	3.2	3.2	3.2	
Offset voltage (min./max.) V_0	mV	-25	+25									
Nonlinearity (typ.) L	%FS	±1	±0.75	±0.5			±0.25					
Output span (typ.) V _{Sp} @p _r	mV	25	42	50	100	120	120					
Rated pressure p _r	bar	0.025	0.060	0.100	0.250	0.400	1.000	2.500	6.000	10.00	25.00	
Ordering code for KD types ¹⁾		B58611K1100A001	B58611K1100A002	B58611K1100A003	B58611K1100A004	B58611K1100A005	B58611K1100A006	B58611K1100A007	B58611K1100A008	B58611K1100A009	B58611K1100A010	
Ordering code for KC types ¹⁾ ¹⁾ Rated pressure range 0.025 25.00 Other values on request.	bar.	B58611K1500A007	B58611K1500A008	B58611K1500A009	B58611K1500A010	B58611K1500A011	B58611K1500A012	B58611K1500A013	B58611K1500A014	B58611K1500A015	B58611K1500A016	

AT2							ASB 1200 E SMD	T5100 <u>SMD</u>		
Absol	ute									
Non-a	iggress	ive gas	ses				Non-aggressive gases	Non-aggressive gases		
						m	V, not calibrated, not temperature-compensate	d		
Supply Supply	voltage voltage	V _{DD+} : Pir V _{DD-} : Pir	n 2, Outp n 4, Outp	out volta out volta	ge V _{out+} : ge V _{out-} :	Pin 5, Pin 3	Supply voltage $V_{_{DD+}}$: Pad 4, Output voltage $V_{_{out+}}$: Pad 1, Supply voltage $V_{_{DD-}}$: Pad 2, Output voltage $V_{_{out-}}$: Pad 3	$\begin{array}{l} \text{Output voltage V}_{\text{out}+} : \text{Pin 1, Ground GND: Pin 2,} \\ \text{Output voltage V}_{\text{out}-} : \text{Pin 3, Supply voltage V}_{\text{DD}} : \text{Pin 4} \end{array}$		
012.6 011.6 011.6 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0							4 3 1 2 0.5 1.7 1.7 $1050028-3$ 4 4 4 4 4 4 4 4 4 4	1.7 4 3 4 4 5 5 5 5 5 5 5 5 5 5 5 5 5		
-40	. +125						-40 +125	-40 +125		
-30	. +85						-40 +85	-40 +85		
10							10	10		
23							24	24		
5							6	6		
-2.2							-2.2	-2.2		
5							5	5		
2.6	4.0						2.6 4.0	2.6 4.0		
-30	. +30						-30 +30	0 +30		
±0.2							±0.3	±0.3		
120							120	120		
1.600	2.500	4.000	6.000	10.00	16.00	25.00	1.200	1.200		
B58610T4600A001	B58610T4600A002	B58610T4600A003	B58610T4600A004	B58610T4600A005	B58610T4600A006	B58610T4600A007	B58610A000A001	Upon request		

Technical data

loolinioal data										
Туре	CAU-T with stainless steel casing, voltage output									
Pressure measurement	Absolute	Gauge	Gauge, symmetr.							
Measured media	Non-aggressive gases	Non-aggressive fluids and gases								
Output signal	0.5 V 4	.5 V, calibrated and temperature-compens	sated							
Terminal assignment	Supply voltage V_{cC} : Pin 1 (brown), Output voltage V _A : Pin 2 (white) Ground GND: Pin 3 (blue), Ground (Kelvin guidance) GND: Pin 4 (black)									

Dimensional drawings in mm



A shielded 4-pole cable (2 m) with a modified (pressure equalisation) female M12 locking plug is included in delivery

Maximum ratings																			
Storage temperature T_{st}	°C	-30	+8	35			-30	+8	35						-30	+8	5		
Operating temperature T _a	°C	-25	+8	35			-25	+8	35						-25	+8	5		
Compensated range T_{C}	°C	0 +70				0 +70						0	+70						
DC breakdown voltage (min.) V_{is}	V	500					500						500						
Supply voltage (min./max.) V_{CC}	7.5	30				7.5 30						7.5 30							
Supply current (max.) I_{CC} ($I_{A}=0$)	7					7						7							
Signal output current (max.) I _A	mA	2 2								2									
Max. output signal V _{ERR} at sensor failure	V	0.01	0.01 0.01								0.01								
Temperature characteristics \mathbf{V}_{cc}	= 15 V within [·]	T _c																	
Temperature coefficient of offset (typ.) TCV _{A0}	%FS/K	±0.0	015				±0.0	015							±0.0	015			
Temperature coefficient of span (typ.) TCV _{FS} %FS/K)15				±0.0	015							±0.0)15			
Characteristics $T_a = 25 \text{ °C}$, $V_{cc} = 7$	15 V, I _A < 0.1 m	۱A																	
Response time (typ.) t_{10-90}	ms	1					1								1				
Offset V _{A0}	V	0.5 ±0.015				0.5 ±0.015						2.5 ±0.015							
Nonlinearity (typ.) L	%FS	±0.1					±0.1						±0.25						
Output span V _{FS}	V	4.0	±0.01	5			4.0 ±0.015							4.0 ±0.015					
Rated pressure p _r	bar	1.000	2.500	6.000	10.00	25.00	0.100	0.250	0.400	1.000	2.500	6.000	10.00	25.00	0.100	0.250	0.400	1.000	
Ordering code ¹⁾		20H5810A018	20H5810A019	20H5810A020	20H5810A021	20H5810A022	21H5810A023	21H5810A024	21H5810A025	21H5810A026	21H5810A027	21H5810A028	21H5810A029	21H5810A030	23H5810A031	23H5810A032	23H5810A033	23H5810A034	
¹⁾ Rated pressure range 0.100 25.00 bar. Other values on request.			B586																

16

CAU-T without casing, voltage output																		
Absolu	ıte				Gauge								Gauge, symmetr.					
Non-ag	gressive	gases			Non-ag	gressive	fluids ar	nd gases										
					0.5 V	. 4.5 V, c	alibrated	d and ter	nperatu	re-comp	ensated							
					1	Supp Outp	oly voltag ut signal	ge: V _{cc} , ((referen	Ground: ce to GN	GND, ID): V _A								
17 ⁺¹ 6+1			oc IND A Solder pins	ing					19 ⁻¹ 6-1	M5 AK Ø18 ⁺ 0 0 0 0		Soldering						
-40	+105				-40	+105							-40	+105				
-25	+85				-25	+85							-25	+85				
0 +7	0				0 +7	0							0 +7	0				
500					500 500													
4.75	5.5				4.75 5.5									5.5				
7					7									7				
2					2									2				
0.01					0.01									0.01				
0.01														0.01				
Tempe	rature o	haracte	eristics V	/ _{cc} = 5 V	within	Г _с							1					
±0.015					±0.015								±0.015					
±0.015					±0.015									±0.015				
Charae	cteristic	s T _a = 2	5 °C, V _{cc}	, = 5 V, I	< 0.1 m	A												
1					1								1					
0.5 ±0.	015				0.5 ±0.015									015				
±0.1					±0.1								±0.25					
4.0 +0	015				4.0 + 0	015							4.0 +0	015				
1.000	2.500	6.000	10.00	25.00	0.100	0.250	0.400	1.000	2,500	6.000	10.00	25.00	0.100	0.250	0.400	1.000		
1.000	2.000	0.000	10.00	20.00	0.100	0.200	0.400	1.000	2.000	0.000	10.00	20.00	0.100	0.200	0.400	1.000		
100	002	03	004	05	900	207	308	600	010	011	012	013	014	015	016	017		
OAC	OAC	OAC	OAC	OAC	OAL	OA(OAI	OA(OA(OA(OA(OAI	OAI	OA(OAI	OAI		
51	151	151	151	151	<u> 35</u> 1	051	351	051	051	051	351	<u> 351</u>	<u> 051</u>	051	351	351		
DTO	DTO	DTO	DTO	DTO	1K(1K(1XL	1K(1K(1K(1K(1K(3K(3K(3K(3K(
362	362	362	362	362	362	362	862	362	362	362	362	862	362	362	862	362		
B5	B5	B5	B5	B5	B5	B5{	B5	B5	B5	B5	B5	B5	B5	B5{	B5	B5(

Technical data																			
Туре		CAU-T with stainless steel casing, current output																	
Pressure measurement		Abs	olute)			Gau	ige							Gau	ige, s	ymme	ətr.	
Measured media		Non	-aggr	essive	gase	S	Non	-aggr	essive	e fluid	s and	gase	s						
Output signal					4 mA	20) mA,	calib	rated	and	temp	eratu	re-co	mper	sated	1			
Terminal assignment						Posi N	tive s legat	supply ive su	/ volta upply	age I+ volta	- (V _{cc}) ge I–:): Pin Pin 3	1 (bro 3 (blue	own), ∋)					
Dimensional drawings in mm																			
		022		ø15	O is	-Ring se include	G1/8" G1/8" ISO228	6.	5		5	0			9.5	Ver	4 1 nt hole 2 TDS0	3 2 2 mm 220-0-е	
		A mo M1	A shielded 4-pole cable (2 m) with a modified (pressure equalisation) female M12 locking plug is included in delivery																
Maximum ratings																			
Storage temperature T _{st}	°C	-30	+8	5			-30	+8	35						-30	+8	35		
Operating temperature T _a	°C	-25 +85				-25	+8	35						-25 +85					
Compensated range T _c	°C	0 +70				0 +70						0 +70							
DC breakdown voltage (min.) V _{is}	V	500				500						500							
Supply voltage (min./max.) V _{cc}	V	10.	30				10 30						10 30						
Current limit locmar	hА	23					23						23						
Max. working resistance R_L $R_L = (V_s-10 V) / 0.02 A$	Ω	1000					1000						1000						
Max. output signal I _{ERR} m at sensor failure	ηА	3	3 3							3									
Temperature characteristics V_{cc} = 15 V with	nin 1	с																	
Temperature coefficient of offset (typ.) TCI _{CC0} %FS.	/K	±0.0)15				±0.015						±0.0)15					
Temperature coefficient of span (typ.) TCI _{FS} %FS	/K	±0.0)15				±0.015 ±0.015												
Characteristics $T_a = 25 \text{ °C}$, $V_{cc} = 15 \text{ V}$, $R_L = 1$	00 9	Ω																	
Response time (typ.) t ₁₀₋₉₀ n	ns	1					1								1				
Offset I _{CC0} m	пA	4 ±0	.08				4 ±0	0.08							12 ±	:0.08			
Nonlinearity (typ.) L %F	=S	±0.1					±0.1	1							±0.2	25			
Output span I _{FS} m	ηА	16 ±	80.0				16 ±	±0.08							16 ±0.08				
Rated pressure p, ba	ar	1.000 2.500 6.000 10.00 25.00					0.100	0.250	0.400	1.000	2.500	6.000	10.00	25.00	0 0.100 0.250 0.400 1.000				
Ordering code ¹⁾		3620H5820A035	3620H5820A036	3620H5820A037	3620H5820A038	3620H5820A039	3621H5820A040	3621H5820A041	3621H5820A042	3621H5820A043	3621H5820A044	3621H5820A045	3621H5820A046	3621H5820A047	3623H5820A048	3623H5820A049	3623H5820A050	3623H5820A051	
Other values on request.	B58	B58	B58	B58	B58	B58	B58	B58	B58	B58	B56	B56	B58	B58	B56	B58	B58		

						CAU-T	without	casing,	current	output		,								
Absolu	ıte				Gauge								Gauge, symmetr.							
Non-ag	gressive	gases			Non-ag	gressive	fluids ar	d gases												
					4 mA	20 mA,	calibrate	d and te	mperatu	ire-com	censated	b								
						1 1	Positive Vegative	supply v supply \	oltage: I /oltage:	+ _										
17 ⁺¹ 6±1		M5 AT TD50022-8	Solderin 7 pins	g	$\begin{array}{c} & M5 \\ \hline \\ $								[′] <u>CC</u>) → R _L → OGND + V _{RL} TDS0021-9							
-40	+105				-40	+105							-40	+105						
-25	+85				-25	+85							-25	+85						
0 +7	'0				0 +7	0							0 +70							
500					500 500															
10 3	80				10 30									0						
23					23			23												
1000					1000									1000						
2					3									3						
5					5									5						
					1								1							
±0.015					±0.015								±0.015							
±0.015					±0.015															
													I							
1					1								1							
4 ±0.08	3				4 ±0.08	3		12 ±0.0	08											
±0.1					±0.1								±0.25							
16 ±0.0)8				16 ±0.0)8							16 ±0.0)8						
1.000	2.500	6.000	10.00	25.00	0.100	0.250	0.400	1.000	2.500	6.000	10.00	25.00	0.100	0.250	0.400	1.000				
-	N		4	2	Ţ	Ņ	ņ	4	Ń	9	~	ço	-	N	ņ	4				
00	100	100	JOQ	100	400	400	100	400	300	100	100	100	400	400	400	400				
5204	204	204	204	1204	520	520,	320/	520	320/	520/	520/	520/	520/	520/	320/	520,				
T05	T05	T05	T05	T05	K05	KOS	K05	K05	K05	K05	X05	X05	K05	K05	K05	K05				
320	320	320	320	320	321	321	321	321	321	321	3211	3211	523	323	523	3231				
358(3586	358(3586	358(358(3586	358(3586	358(358(358(358(358(3586	358(358(
ш					ш	Ш			ш	ш	Ш									

Technical data											
Туре	AC-T series, LN type	es, voltage output	AC-	T serie	es, KD) type	s, vol	tage (outpu	t	
Pressure measurement	Absolute		Gau	ge			Gau	ge, sy	mme	tr.	
Measured media	Non-aggressive gase	es	Non	-aggr	essive	fluids	s and	gases	6		
Output signal	0.5 V	4.5 V, calibrated and	d temp	oeratu	ire-co	mpen	satec				
Terminal assignment	5	Supply voltage V _{cc} : Pin Output signal (referen	n 1, Gr nce to	ound GND	GND:) V _A : F	Pin 2 Pin 3	,				
Dimensional drawings in mm	For PCB mounting.	Terminal assignment Ø0.8 (Ø32 mil) 1 0 0 0 0 0 0 0 0 0 0 0 0 0	For P	CB mo	Unting. 1.8 3 	6 1. 6 6 7 8 0 8 0028-2	7.62 (300 mil) → → → → → → → → → → → → → → → → → → →	rminal a	2 mil) 6 (575 ⊤DSi	8 5 mil)	
Maximum ratings											
Storage temperature T _{et} °C	-40 +105		-40.	+10)5		-40	+10	05		
Operating temperature T ₂ °C	-25+85 -25+85 -25+8						5				
Compensated range T _c °C	0+70 0+70 0.					0	+70				
DC breakdown voltage (min.) V.	500 500						500				
Supply voltage (min /max) V ₁₅	4 75 5 5		4 75	5 4	5		4 75	5	5		-
Supply current (max.) V_{CC}	7		7	0.0	,		7	0.	0		
Signal output current (max.) I mA	2		2				2				-
Max. output signal V _{ERR} V at sensor failure	0.01		0.01				0.01				
Temperature characteristics $V_{cc} = 5 V$ within T			1								
Temperature coefficient											
of offset (typ.) TCV _{A0} %FS/K Temperature coefficient	±0.015		±0.0	15			±0.0	15			
of span (typ.) TCV _{FS} %FS/K	±0.015		±0.0	15			±0.0	15			
Characteristics $T_a = 25 \text{ °C}$, $V_{cc} = 5 \text{ V}$, $I_A < 0.1 \text{ m/s}$	4										
Response time (typ.) t ₁₀₋₉₀ ms	1		1				1				
Offset V _{A0} V	0.5 ±0.015		0.5 ±	0.015	5		2.5 -	±0.015	5		
Nonlinearity (typ.) L %FS	±0.1		±0.1				±0.2	5			
Output span V _{FS} V	4.0 ±0.015		4.0 ±	0.015	5		4.0 =	±0.015	5		
Rated pressure p _r bar	1.000	2.500	0.100	0.250	0.400	1.000	0.100	0.250	0.400	1.000	
Ordering code ¹⁾ ¹⁾ Rated pressure range 0.100 25.00 bar. Other values on request.	B58620L1110A052	B58620L1110A053	B58621K1110A054	B58621K1110A055	B58621K1110A056	B58621K1110A057	B58623K1110A058	B58623K1110A059	B58623K1110A060	B58623K1110A061	

				AC-T se	eries, KC typ	oes, voltage	e output								
Gauge						Gauge, symmetr.									
 Non-aggre	essive fluids	and gases													
			0.5 V	′ 4.5 V, ca	alibrated and	temperatu	re-compens	ated							
				Output si	age v _{cc} : Pin gnal (referer	nce to GND	O(A) =								
				For PCB m	iounting.	Terminal	assignment								
			-#			Ø0.8 ((iju 006) 29.7	Ø 32 mil)								
					1030025-5										
-40 +10)5							-40 +10	5						
-25 +85	5							-25 +85	i						
0+70 0+70															
500								500							
4.75 5.5	5							4.75 5.5	5						
7								7							
2								2							
0.01								0.01							
10.015								0.015							
±0.015								±0.015							
±0.015								±0.015							
1								1							
0.5 ±0.015	5							2.5 ±0.015							
±0.1								±0.25							
4.0 ±0.015	5							4.0 ±0.015							
0.100	0.250	0.400	1.000	2.500	6.000	10.00	25.00	0.100	0.250	0.400	1.000				
962	03	164)65	990	167	908	69	020	171	172	073				
OAC	OAC	OAC	OAC	OAC	OAC	OAC	OAC	OAC	OAC	OAC	OAC				
151	151	151	151	151	151	151	(151	151	151	151	(151				
21K	21K	21K	21K	21K	21K	21K	21K	23K	23K	23K	23K				
586	586	586	586	586	586.	586.	586	586	586	586.	586				
Ú	ä	ä	Ú	Ű	Ú	Ú	ú	Ú	Ú	ú	B				

Technical dataTypeASB 1200 V1 SMDASB 1200 VR SMDPressure measurementAbsoluteAbsoluteMeasured mediaNon-aggressive gasesNon-aggressive gasesOutput signal0...1V, calibrated and temperature-compensated10...90% V_{CC}, calibrated and temp.-compensat.Terminal assignmentSupply voltage V_{CC}: Pad 4, Output voltage V_A: Pad 3, Ground GND: Pad 2Dimensional drawings in mm





Maximum ratings							
Storage temperature T _{st}	°C	-40 +125	-40 +125				
Operating temperature T _a	°C	-40 +85	-40 +85				
Compensated range T_c	°C	0 +70	0 +70				
DC breakdown voltage (min.) V _{is}	V	500	500				
Supply voltage (min./max.) V_{CC}	V	2.7 5.5	2.7 5.5				
Supply current (max.) I_{CC} ($I_{A}=0$)	mA	5	5				
Signal output current (max.) I _A	mA	2	2				
Resolution	bit	11	11				
Temperature characteristics $V_{cc} = 3$	5 V within T	0					
Temperature coefficient of offset (typ.) TCV _{A0}	%FS/K	±0.015	±0.015				
Temperature coefficient of span (typ.) TCV _{FS}	%FS/K	±0.015	±0.015				
Characteristics $T_a = 25 \degree C$, $V_{CC} = 5 V$	/, I _A < 0.1 m/	A					
Response time (typ.) t ₁₀₋₉₀	ms	2	2				
Offset V _{A0}	V	0@200 mbar	10% V _{cc} @200 mbar				
Nonlinearity (typ.) L	%FS	±0.1	±0.1				
Output span V _{FS}	V	1	80% V _{cc}				
			55				
Rated pressure range	bar	0.2 1.2	0.2 1.2				
Rated pressure range Ordering code ¹⁾	bar	0.2 1.2 LOOPOLOOPO2098	0.2 1.2 200000000000000000000000000000000000				

	T5300 SMD	T5400 SMD
	Absolute	Absolute
	Non-aggressive gases	Non-agaressive gases
	Serial bus, I ² C, SPI	Serial bus, I ² C, SPI
	Ground GND: Pad 1 and 4, INT/SS: Pad 2, V_{DD} : Pad 3, SCL/SCLK: Pad 5, SDA/MISO: Pad 6	V _{DD} : Pad 1, CAP: Pad 2, Ground GND: Pad 3, PROG: Pad 4, RST/SS: Pad 5, MOSI: Pad 6, SDA/MISO: Pad 7, SCL/SCLK: Pad 8
	2.06 2.06 CO.05 2.6±0.1 5 4 4 4 4 4 4 4 4 4 4 4 4 4	2.7 Type a 7 6 5 designation EPCOS J2LN 1 2 3 4 TDS0067-8
Í	-40 +125	-40 +125
	-40 +85	-40 +85
	customer-specific	customer-specific
	-	-
	2.7 5.5	1.8 3.6
	3	2
	_	_
	14	16
	-	-
	-	-
	-	-
	-	-
	-	-
	-	-
	0.3 1.1	0.3 1.1
	Upon request	Upon request

Description of Terms

Characteristic curve

The key parameters of the characteristic curve are described below:



Offset voltage $V_0 = V_A(p_0)$

The output voltage V_A at zero pressure, known as the offset voltage, typically varies between $\pm 25 \text{ mV}^{1)}$ due to the spread of the technological parameters.

Sensitivity $S = (V_r - V_0) / (p_r - p_0)$

The sensitivity is the quotient of the changes of the output voltage and the applied pressure. Thinner diaphragms and larger surfaces increase the sensitivity and decrease the loadbearing capacity of the diaphragm. Every design is therefore a compromise between high sensitivity and a sufficient pressure overload factor.

Depending on the pressure range, the sensitivity extends between 0.5 and 1800 mV/bar¹). The spread of the technological parameters means that the sensitivity varies within a single pressure range.

 $\overline{ ^{1)} \text{ At } V_{DD} = 5 \text{ V voltage source} }$ $\overline{ ^{2)} \text{ FS} = V_r - V_0 \text{ (full scale)}$

24

Nonlinearity

 $L = (V_z - V_0) / (V_r - V_0) - (p_z - p_0) / (p_r - p_0)$

The nonlinearity describes the deflection of the characteristic curve or the deviation from an ideal straight line. The above formula calculates the nonlinearity by the end-point method. Depending on the pressure range, the nonlinearity typically varies from ± 0.1 to $\pm 1.0\%$ FS²⁾. In many cases, the nonlinearity is preserved despite the hysteresis error, as this is very small in comparative terms.

Hysteresis

For an output signal indicating the same pressure, this represents the greatest difference between measurements made in the direction of increasing and (subsequently) decreasing pressure. This error cannot be determined or compensated. However, the effect is very small and can be neglected in most applications.

Temperature effects

The offset, sensitivity and bridge resistance are functions of the temperature:

Offset V₀

 $V_0 = V_0(25 \ ^{\circ}C) + TCV_0 \cdot (\vartheta - 25 \ ^{\circ}C) \cdot V_{DD}$

The temperature coefficient of the offset voltage typically varies between $\pm 4 \mu V/VK$ depending on the technological parameters. This effect can be neglected in most applications.

Sensitivity S

$$\begin{split} & \mathsf{S}(\vartheta) = \mathsf{S}(25\ ^\circ \mathsf{C}) \cdot \left[1\!+\!\alpha_{\scriptscriptstyle \mathsf{S}} \cdot (\vartheta\!-\!25\ ^\circ \mathsf{C}) + \right. \\ & \beta_{\scriptscriptstyle \mathsf{S}} \cdot (\vartheta\!-\!25\ ^\circ \mathsf{C})^2] \end{split}$$

The temperature coefficient of the sensitivity is much more significant. Depending on the technological parameters, a typical value of $\alpha_{\rm S}$ ranges between –3.1 and –1.8 \cdot 10⁻³/K. The sensitivity thus decreases with temperature rise. A typical value of $\beta_{\rm S}$ is 6 \cdot 10⁻⁶/K².

Bridge resistance R_s

$$\begin{split} \mathsf{R}_{\mathsf{S}}(\vartheta) &= \mathsf{R}_{\mathsf{S}}(25\ ^{\circ}\text{C}) \cdot [1 + \alpha_{\mathsf{RS}} \cdot \\ (\vartheta {-} 25\ ^{\circ}\text{C}) + \beta_{\mathsf{RS}} \cdot (\vartheta {-} 25\ ^{\circ}\text{C})^2] \end{split}$$

The bridge resistance is directly proportional to the temperature (at 25 °C, 3 k Ω and 5 k Ω). Depending on the technological parameters, a typical value of α_{RS} ranges between 2.0 and 2.5 \cdot 10⁻³/K. A typical value of β_{RS} is 6 \cdot 10⁻⁶/K².

Cautions and Warnings

Storage (general)

All pressure sensors should be stored in their original packaging. They should not be placed in harmful environments such as corrosive gases nor exposed to heat or direct sunlight, which may cause deformations. Similar effects may result from extreme storage temperatures and climatic conditions. Avoid storing the sensor dies in an environment where condensation may form or in a location exposed to corrosive gases, which will adversely affect their performance. Plastic materials should not be used for wrapping/packing when storing or transporting these dies, as they may become charged. Pressure sensor dies should be used soon after opening their seal and packaging.

Operation (general)

Media compatibility with the pressure sensors must be ensured to prevent their failure. The use of other media can cause damage and malfunction. Never use pressure sensors in atmospheres containing explosive liquids or gases.

Ensure pressure equalization to the environment, if gauge pressure sensors are used. Avoid operating the pressure sensors in an environment where condensation may form or in a location exposed to corrosive gases. These environments adversely affect their performance.

If the operating pressure is not within the rated pressure range, it may change the output characteristics. This may also happen with pressure sensor dies if an incorrect mounting method is used. Be sure that the applicable pressure does not exceed the overpressure, as it may damage the pressure sensor.

Do not exceed the maximum rated supply voltage nor the rated storage temperature range, as it may damage the pressure sensor.

Temperature variations in both the ambient conditions and the media (liquid or gas) can affect the accuracy of the output signal from the pressure sensors. Be sure to check the operating temperature range and thermal error specification of the pressure sensors to determine their suitability for the application.

Connections must be wired in accordance with the terminal assignment specified in the data sheets. Care should be taken as reversed pin connections can damage the pressure transmitters or degrade their performance. Contact between the pressure sensor terminals and metals or other materials may cause errors in the output characteristics.

Design notes (dies)

This specification describes the mechanical, electrical and physical requirements of a piezoresistive sensor die for measuring pressure. The specified parameters are valid for the pressure sensor die with pressure application either to the front or back side of the diaphragm as described in the data sheet. Pressure application to the other side may result in differing data. Most of the parameters are influenced by assembly conditions. Hence these parameters and the reliability have to be specified for each specific application and tested over its temperature range by the customer.

Handling/Mounting (dies)

Pressure sensor dies should be handled appropriately and not be touched with bare hands. They should only be picked up manually by the sides using tweezers. Their top surface should never be touched with tweezers. Latex gloves should not be used for handling them, as this will inhibit the curing of the adhesive used to bond the die to the carrier. When handling, be careful to avoid cuts caused by the sharp-edged terminals. The sensor die must not be contaminated during manufacturing processes (gluing, soldering, silk-screen process).

The package of pressure sensor dies should not to be opened until the die is mounted and should be closed after use. The sensor die must not be cleaned. The sensor die must not be damaged during the assembly process (especially scratches on the diaphragm).

Soldering (transducers, transmitters)

The thermal capacity of pressure sensors is normally low, so steps should be taken to minimize the effects of external heat. High temperatures may lead to damage or changes in characteristics.

A non-corrosive type of flux resin should normally be used and complete removal of the flux is recommended.

Avoid rapid cooling due to dipping in solvent. Note that the output signal may change if pressure is applied to the terminals during soldering.

This listing does not claim to be complete, but merely reflects the experience of EPCOS AG.

Get in Contact

Europe

Austria, Bulgaria, Greece, Macedonia, Montenegro, Romania, Serbia EPCOS OHG Vienna T +43 51 70 72 56 30 F +43 51 70 75 56 45 sales.csee@epcos.com

Czech Republic EPCOS s.r.o. Prague T +420 2 33 03 22 81 F +420 2 33 03 22 89 sales.czech@epcos.com

Finland EPCOS Nordic OY Espoo T +358 10 5 11 32 00 F +358 10 5 11 22 85 sales.nordic@epcos.com

France, Belgium, Luxembourg, Malta, Netherlands FPCOS SAS Saint-Denis/France T +33 1 49 46 67 89 F +33 1 49 46 67 67 sales.france@epcos.com

Germany, Liechtenstein, Switzerland EPCOS AG **Customer Service** Munich T (D) 0180 500 33 48 (0.14 Euro/min.) (CH) 08 48 37 26 71 F +49 89 63 62 80 10 sales.germany@epcos.com

Hungary EPCOS Elektronikai Alkatrész Kft Budapest T +36 1 436 07 20 F +36 1 436 07 21 sales.hungary@epcos.com

Italy

Infineon Technologies Italia s.r.l. Settore EPCOS Milan T +39 02 25 20 44 265 F +39 02 25 20 44 380

sales.italy@epcos.com

Poland, Latvia, Lithuania EPCOS Polska Sp. z o.o Warsaw T +48 22 24 60 409 F +48 22 24 60 400

sales.poland@epcos.com Portugal

EPCOS 2 Portugal LDA Évora T +351 91 75 67 927 F +351 21 49 33 476 sales.portugal@epcos.com Russia, Belarus, Kazakhstan, Moldavia, Ukraine 000 Siemens **EPCOS** Division Moscow T +7 495 7 37 24 17 / 18 F +7 495 7 37 23 46 sales.cis@epcos.com

Slovakia **EPCOS Sales Representative** Dolný Kubín T +42 1 43 5 82 36 73 F +42 1 43 5 82 37 33 sales.slovakia@epcos.com

Slovenia, Croatia, Bosnia & Herzegovina EPCOS Sales Representative Škofljica/Slovenia T +386 599 56 35 3 F +386 599 56 35 4 sales.slovenia@epcos.com

Spain **EPCOS Electronic Components** S.A. Getafe T +34 91 514 71 61 F +34 91 514 70 14 sales.iberia@epcos.com

Sweden, Estonia, Iceland, Denmark, Norway EPCOS Nordic AB Kista/Sweden T +46 8 4 77 27 00 F +46 8 4 77 27 01 sales.nordic@epcos.com

Turkey EPCOS AG Liaison Office Istanbul т +90 216 5 69 81 01 F +90 216 4 64 07 56 sales.turkey@epcos.com

United Kingdom, Ireland EPCOS UK Ltd. Bracknell T +44 13 44 38 15 10 F +44 13 44 38 15 12 sales.uk@epcos.com

Asia

Afghanistan, Iran, Iraq, Jordan, Lebanon, Syria EPCOS AG Liaison Office Istanbul/Turkey T +90 216 5 69 81 01 F +90 216 4 64 07 56 sales.turkey@epcos.com

China EPCOS (Shanghai) Ltd. Shanghai T +86 21 33 02 46 20 F +86 21 63 91 68 89 sales.cn@epcos.com

Hong Kong EPCOS Limited Hong Kong T +85 2 31 01 56 00 F +85 2 31 01 56 46 sales.cn@epcos.com

India, Bahrain, Bangladesh, Kuwait, Nepal, Oman, Pakistan, Qatar, Saudi Arabia, Sri Lanka, United Arab Emirates EPCOS India Private Ltd. Bangalore T +91 80 40 39 06 15

F +91 80 40 39 06 03 sales.in@epcos.com Israel

Nisko Projects Electronics & Communications (1999) Ltd. Tel Aviv T +972 37 65 73 00 F +972 37 65 73 33 sales.israel@epcos.com

Japan EPCOS KK Yokohama T +81 45 4 78 72 00 F +81 45 4 78 72 25 sales.jp@epcos.com

Korea EPCOS Korea LLC Seoul T +82 2 21 56 68 18 F +82 2 21 56 68 98 sales.kr@epcos.com

Malaysia EPCOS SDN. BHD. Kuala Lumpur T +60 3 79 60 81 80

F +60 3 79 60 81 82 sales.asean@epcos.com

Philippines Siemens Inc.

Manila T +63 2 8 78 94 44 F +63 2 8 78 94 40 sales.asean@epcos.com

Singapore, Indonesia, Thailand, Vietnam EPCOS PTE LTD Singapore T +65 68 41 20 11 F +65 67 44 69 92 sales.asean@epcos.com

Taiwan EPCOS Taiwan Co. Ltd. Taipei T +886 2 26 55 76 76

F +886 2 55 59 02 88 sales.tw@epcos.com

Americas

USA, Canada, Mexico EPCOS, Inc. Iselin, NJ, USA T +1 732 9 06 43 00 F +1 732 9 06 43 95 sales.usa@epcos.com

South America EPCOS do Brasil Ltda. São Paulo T +55 11 36 12 50 30 F +55 11 36 12 50 30 sales.br@epcos.com

Australia

Australia, New Zealand Electronic Component Solutions Pty Ltd Melbourne T +61 3 85 61 19 99 F +61 3 95 74 70 55 sales.au@epcos.com

Africa

Republic of South Africa Electrocomp (PTY) Ltd. Sandton T +27 11 458 90 00 32 F +27 11 458 90 34 sales.southernafrica@epcos.com

Egypt

Siemens Ltd. **EPCOS** Division Cairo T +202 3 333 36 69

F +202 3 333 36 07 sales.egypt@epcos.com

Morocco, Tunisia EPCOS SAS Saint-Denis/France T +33 1 49 46 67 89 F +33 1 49 46 67 67 sales.france@epcos.com

08/09

The addresses of our worldwide distributors and regional sales offices are available at www.epcos.com/sales

© EPCOS AG 2009, Corporate Center, P.O.Box 80 17 09, 81617 Munich, Germany, T +49 89 636 09, F +49 89 636 226 89 Reproduction, publication and dissemination of this publication and the information contained therein without EPCOS' prior express consent is prohibited.



© EPCOS AG 2009 · Corporate Center · Edition 08/2009 Ordering No. EPC:69004-7600 · Printed in Germany · PP 08095.